International **ISPR** Rectifier

SCHOTTKY RECTIFIER

1N5817

1.0 Amp

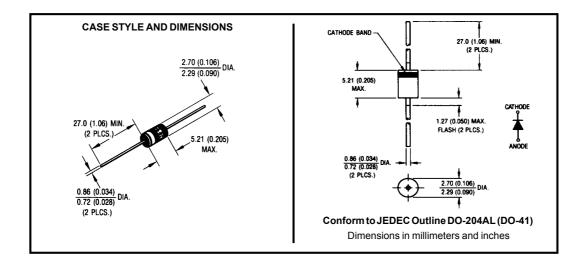
Major Ratings and Characteristics

Characteristics	1N5817	Units
I _{F(AV)} Rectangular waveform	1.0	A
V _{RRM}	20	V
I _{FSM} @tp=5µssine	240	А
V _F @1Apk,T _J =25	°C 0.45	V
T _J range	-65 to 150	°C

Description/Features

The 1N5817 axial leaded Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. Typical applications are in switching power supplies, converters, free-wheeling diodes, and reverse battery protection.

- Low profile, axial leaded outline
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability



1N5817

Bulletin PD-20646 rev. A 02/02

International **IOR** Rectifier

Voltage Ratings

Partnumber	1N5817
V _R Max. DC Reverse Voltage (V)	20
V _{RWM} Max. Working Peak Reverse Voltage (V)	20

Absolute Maximum Ratings

	Parameters	1N5817	Units	Conditions	
I _{F(AV)}	Max.AverageForwardCurrent	1.0	А	50%dutycycle@T _L =138°C,re	ectangularwaveform
I _{FSM}	Max.PeakOneCycleNon-Repetitive	240	A		Following any rated
	SurgeCurrent,@T _J =25°C	40		10ms Sine or 6ms Rect. pulse	load condition and with rated V _{RRM} applied

Electrical Specifications

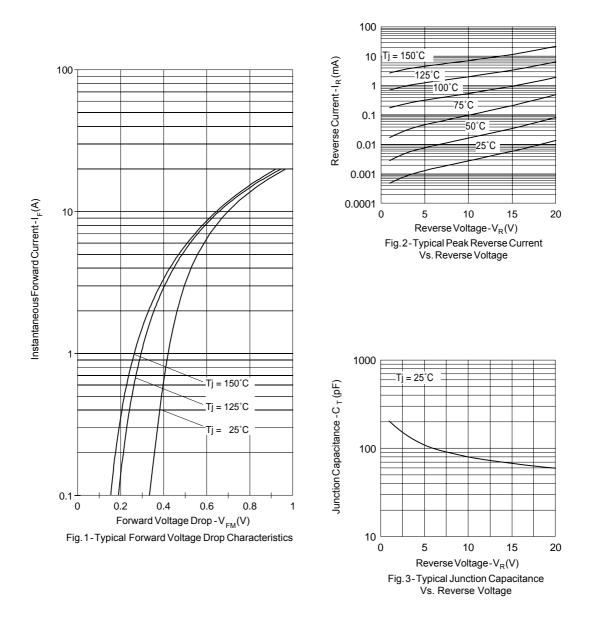
	Parameters	Тур.	Max.	Units	Conditio	ns
V _{FM}	Max. Forward Voltage Drop (1)	0.42	0.45	V	@ 1A	T,= 25 °C
		0.50	0.75	V	@ 3A	1 _J = 25 C
I _{RM}	Max. Reverse Leakage Current (1)	0.012	1.0	mA	T _J = 25 °C	V_{p} = rated V_{p}
		2.0	10	mA	T _J = 100 °C	V _R - Micd V _R
CT	Typical Junction Capacitance	110	-	pF	$V_R = 5V_{DC}$ (te	est signal range 100kHz to
					1Mhz), @ 25	°C
L _S	Typical Series Inductance	8.0	-	nH	Measured lead	d to lead 5mm from package body
dv/dt	Max. Voltage Rate of Change	-	10000	V/ µs	$(Rated V_R)$	

(1) Pulse Width < 300µs, Duty Cycle <2%

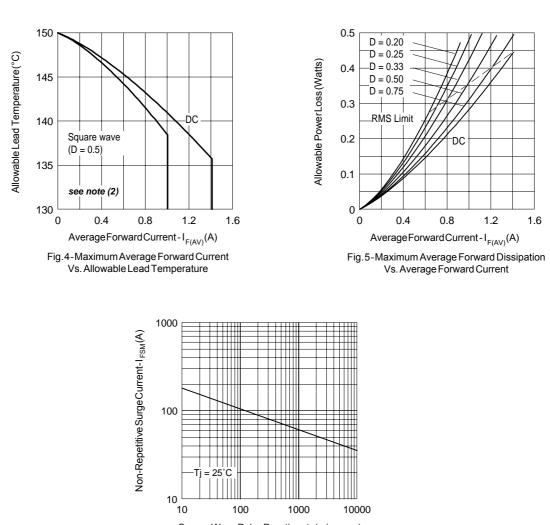
Thermal-Mechanical Specifications

	Parameters	1N5817	Units	Conditions
TJ	Max.JunctionTemperatureRange (2)	-65 to 150	°C	
T _{stg}	Max. Storage Temperature Range	-65 to 150	°C	
R _{thJL}	Max. Thermal Resistance Junction to Lead	32	°C/W	DC operation, Lead lenght = 1/8 inch.
R _{thJA}	Max.ThermalResistanceJunction toAmbient	100	°C/W	DC operation, without cooling fin
Wt	Approximate Weight	0.33(0.012)	gr(oz)	
	Case Style	DO-204AL	(DO-41)	

 $\frac{(2) \, dPtot}{dTj} < \frac{1}{Rth(j-a)} \quad \text{thermal runaway condition for a diode on its own heatsink}$



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SquareWavePulseDuration-t_p(microsec)

Fig. 6-Maximum Peak Surge Forward Current Vs. Pulse Duration

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ICR Rectifier	-

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Marking & Identification	Ordering Information
Each device has marking and identification on two rows. - The first row designates the device as manufactured by International Rectifier as indicated by the letters "IR", then Part Number. - The second row shows the data code: Year and Week. See below marking diagram.	IR1N5817 TR - TAPE AND REEL WHEN ORDERING, INDICATE THE PART NUMBER AND THE QUANTITY (IN MULTIPLES OF 5000 PIECES). EXAMPLE: IR1N5817 TR - 10000 PIECES
FIRST ROW IR 1N5817	IR1N5817 SERIES - BULK QUANTITIES
SECOND ROW Date Code YY WW	WHENORDERING,INDICATETHEPARTNUMBER AND THE QUANTITY (IN MULTIPLE OF 1000 PIECES)
	EXAMPLE: IR 1N5817 - 2000 PIECES

Data and specifications subject to change without notice. This product has been designed for Industrial Level. Qualification Standards can be found on IR's Web site.

International

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